









	<h2>RFD8P05SM</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">RFD8P05SM</a></p> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 50V 8A TO-252AA</p> <p><b>Datenblätter:</b>  <a href="#">RFD8P05SM.pdf</a></p> <p><b>RoHs Status:</b> Enthält Blei / RoHS nicht konform</p> <p><b>Lagerzustand:</b> New original, 40145 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">RFD8P05SM</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET P-CH 50V 8A TO-252AA
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	40145 pcs Stock
detaillierte Beschreibung	P-Channel 50V 8A (Tc) Surface Mount TO-252AA
Serie	-
Technologie	MOSFET (Metal Oxide)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252AA
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	50V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8A (Tc)
Rds On (Max) @ Id, Vgs	300 mOhm @ 8A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	80nC @ 20V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Contains lead / RoHS non-compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)


RFD8P05SM ist neu im Original, Suche RFD8P05SM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RFD8P05SM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage RFD8P05SM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>RFD77808</b> RF Digital TMG4903 RGB AND PROXIMITY KIT</p>	 <p><b>RFD8P05</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 50V 8A I-PAK</p>	 <p><b>RFD8P06ESM</b> F RFD8P06ESM F</p>	 <p><b>RFD8P06E</b> FSC RFD8P06E FSC</p>
 <p><b>RFD8P05</b> Fairchild/ON Semiconductor MOSFET P-CH 50V 8A I-PAK</p>	 <p><b>RFD77809</b> RF Digital CCS811 CO2 AND VOC IAQ KIT</p>	 <p><b>RFD8P05SM9A</b> INTERSI RFD8P05SM9A INTERSI</p>	 <p><b>RFD77810</b> RF Digital AS6200 PRECISION TEMPERATURE KIT</p>

### heiße Teile

Mehr

 RFD16N05LSM9A	 RFD16N05SM	 RFD16N05SM	 RFD16N05SM9A	 RFD16N05SM9A
 RFD16N06	 RFD16N06L	 RFD16N06LESMS	 RFD16N06LESMS9A	 RFD16N06LESMS9A
 RFD16N06SM9A	 RFD20N03SM	 RFD20N03SM9A	 RFD3055L	 RFD3055LE
 RFD3055LE	 RFD3055LESMS	 RFD3055LESMS	 RFD3055LESMS9A	 RFD3055LESMS9A
 RFD3055LESMS9AS2568	 RFD3055RLESMS96	 RFD3055RLESMS9A	 RFD3055SM	 RFD3055SM
 RFD3055SM9A	 RFD3055SM9A	 RFD4N06LSM	 RFD8P05SM	 RFD8P05SM9A
 RFD8P06ESM	 RFD8P06ESMS9A	 RFD8P06LESMS	 RFD8P06LESMS9AR4407	 RFD8P06SM
 RFD8P06TM	 RFDA2026	 RFDA2026TR13	 RFDIP1608060T1T	 RFDIP1608060TM7T62
 RFDIP1608060TM8T62	 RFDIP160806ALM2T66	 RFDIP160806BLM5T62	 RFDIP160806BLM6T25	 RFDIP2012050L7T
 RFDIP2012050LPT	 RFDIP2012070G57N2T	 RFDIP2012100L0T	 RFDIP2012100L1T	 RFDIP2520080TM0T62

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